Technical Data Data Sheet 3833, Rev. - **Green Products**

300CNQ035/300CNQ040-G/300CNQ045-G SCHOTTKY RECTIFIER

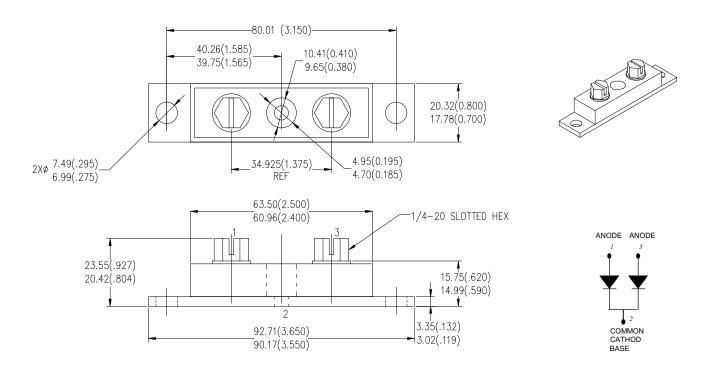
Applications:

- High current switching power supply Plating power supply Free-Wheeling diodes
- Reverse battery protection Converters UPS System Welding

Features:

- 150 °C T_J operation
- Center tap module
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Green Products in Compliance with the RoHS Directive

Mechanical Dimensions: In Inches / mm



PRM4(Non-Isolated)



Data Sheet 3833, Rev. - **Maximum Ratings**:

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Characteristics	Symbol	Condition	Max.		Units
Peak Inverse Voltage	V_{RWM}	-	35(300CNQ035-G) 40(300CNQ040-G) 45(300CNQ045-G)		V
Max. Average Forward	$I_{F(AV)}$	50% duty cycle @T _C = 104 °C,	150	per leg	Α
Current		rectangular wave form	300	per device	
Max. Peak One Cycle Non-Repetitive Surge Current (per leg)	I _{FSM}	8.3 ms, half Sine pulse	2880		А
Non-Repetitive Avalanche Energy (per leg)	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 30 \text{A}, \\ L = 0.67 \text{mH}$	150		mJ
Repetitive Avalanche Current (per leg)	I _{AR}	Current decaying linearly to zero in 1 µsec Frequency limited by T _J max. V _A = 1.5 x V _R typical	30		А

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 150 A, Pulse, T _J = 25 °C	0.61	V
(per leg) *		@ 300 A, Pulse, T _J = 25 °C	0.77	
	V_{F2}	@ 150 A, Pulse, T _J = 125 °C	0.62	V
		@ 300 A, Pulse, T _J = 125 °C	0.75	
Max. Reverse Current (per leg) *	I _{R1}	$@V_R = \text{rated } V_R, T_J = 25 ^{\circ}\text{C}$	15	mA
	I _{R2}	$@V_R = \text{rated } V_R, T_J = 125 ^{\circ}\text{C}$	750	mA
Max. Junction Capacitance	C _T	$@V_R = 5 \text{ V}, T_C = 25 ^{\circ}\text{C}$	7750	pF
(per leg)		f _{SIG} = 1 MHz		
Typical Series Inductance	L _S	Measured lead to lead 5 mm	6.0	nΗ
(per leg)		from package body		
Max. Voltage Rate of Change	dv/dt	-	10,000	V/μs

^{*} Pulse Width < 300µs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification		Units	
Max. Junction Temperature	T _J	-	-55 to +150		°C	
Max. Storage Temperature	T _{stg}	-	-55 to +150		°C	
Maximum Thermal Resistance Junction to Case (per leg)	R _{θJC}	DC operation	0.40		°C/W	
Maximum Thermal Resistance Junction to Case (per package)	R _{θJC}	DC operation	0.20		°C/W	
Maximum Thermal Resistance, Case to Heat Sink	R _{ecs}	Mounting surface, smooth and greased	0.10		°C/W	
Approximate Weight	wt	-	79		g	
Mounting Torque	T _M	-	Mounting Torque Base Terminal Torque	24 (min) 35 (max) 35 (min) 46 (max)	Kg-cm	
Case Style	PRM4 Non-Isolated					

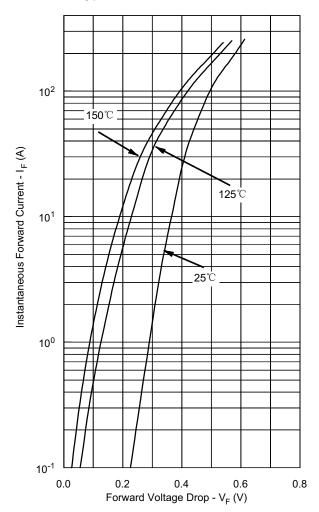
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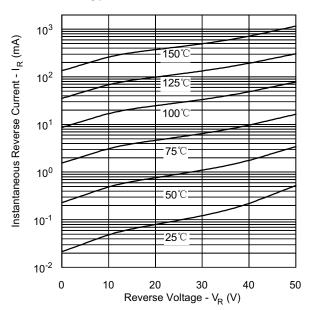
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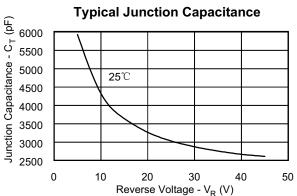
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Typical Forward Characteristics



Typical Reverse Characteristics





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